OIMDB-001

Product Preview

Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Unique Device Numbers for Medical Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	40	V
Forward Power Dissipation @ T _A = 25°C Derate above 25°C	P _F	225 1.8	mW mW/°C
Operating Junction and Storage Temperature Range	T _{J,} T _{stg}	-55 to +150	°C
Forward Continuous Current	IF	120	mA
Forward Surge Current $t \le 1 \text{ s}$ $t \le 10 \text{ ms}$	I _{FSM}	200 600	mA
Thermal Resistance (Note 1) Junction-to-Ambient (Note 2)	$R_{ heta JA}$	508 311	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-4 @ minimum pad.
- 2. FR-4 @ 1.0 x 1.0 in pad.



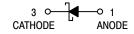
ON Semiconductor®

www.onsemi.com

40 VOLTS SCHOTTKY BARRIER DIODES



SOT-23 (TO-236) CASE 318 STYLE 8



MARKING DIAGRAM



MW= Specific Device Code

M = Date Code*

■ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
0IMDB-001-XTP	SOT-23 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μA)	V _{(BR)R}	40	-	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	C _T	-	5.0	pF
Reverse Leakage (V _R = 25 V)	I _R	-	1.0	μAdc
Forward Voltage (I _F = 1.0 mAdc)	V _F	-	380	mVdc
Forward Voltage (I _F = 10 mAdc)	V _F	-	500	mVdc
Forward Voltage (I _F = 40 mAdc)	V _F	_	1.0	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

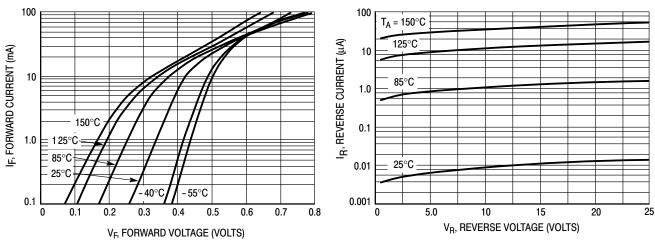


Figure 1. Typical Forward Voltage

Figure 2. Reverse Current versus Reverse Voltage

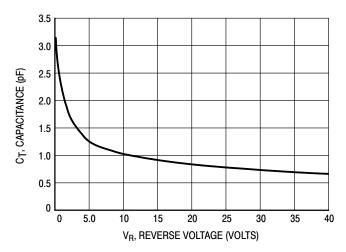
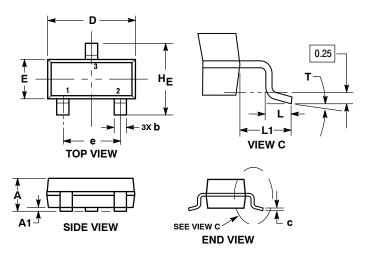


Figure 3. Typical Capacitance

0IMDB-001

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AS**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
- THE BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
 PROTRUSIONS, OR GATE BURRS.

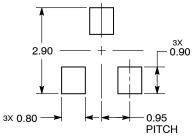
MIN			INCHES		
	NOM	MAX	MIN	NOM	MAX
0.89	1.00	1.11	0.035	0.039	0.044
0.01	0.06	0.10	0.000	0.002	0.004
0.37	0.44	0.50	0.015	0.017	0.020
0.08	0.14	0.20	0.003	0.006	0.008
2.80	2.90	3.04	0.110	0.114	0.120
1.20	1.30	1.40	0.047	0.051	0.055
1.78	1.90	2.04	0.070	0.075	0.080
0.30	0.43	0.55	0.012	0.017	0.022
0.35	0.54	0.69	0.014	0.021	0.027
2.10	2.40	2.64	0.083	0.094	0.104
0°		10°	0°		10°
	0.89 0.01 0.37 0.08 2.80 1.20 1.78 0.30 0.35 2.10	0.89 1.00 0.01 0.06 0.37 0.44 0.08 0.14 2.80 2.90 1.20 1.30 1.78 1.90 0.30 0.43 0.35 0.54 2.10 2.40	0.89 1.00 1.11 0.01 0.06 0.10 0.37 0.44 0.50 0.08 0.14 0.20 2.80 2.90 3.04 1.20 1.30 1.40 1.78 1.90 2.04 0.30 0.43 0.55 0.35 0.54 0.69 2.10 2.40 2.64	0.89 1.00 1.11 0.035 0.01 0.06 0.10 0.000 0.37 0.44 0.50 0.015 0.08 0.14 0.20 0.003 2.80 2.90 3.04 0.110 1.20 1.30 1.40 0.047 1.78 1.90 2.04 0.070 0.30 0.43 0.55 0.012 0.35 0.54 0.69 0.014 2.10 2.40 2.64 0.083	0.89 1.00 1.11 0.035 0.039 0.01 0.06 0.10 0.000 0.002 0.37 0.44 0.50 0.015 0.017 0.08 0.14 0.20 0.003 0.006 2.80 2.90 3.04 0.110 0.114 1.20 1.30 1.40 0.047 0.051 1.78 1.90 2.04 0.070 0.075 0.30 0.43 0.55 0.012 0.017 0.35 0.54 0.69 0.014 0.021 2.10 2.40 2.64 0.083 0.094

STYLE 8:

ANODE

- NO CONNECTION
- CATHODE

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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